MOSPEC

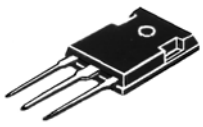
S60D30 Thru S60D60

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

SCHOTTKY BARRIER RECTIFIERS

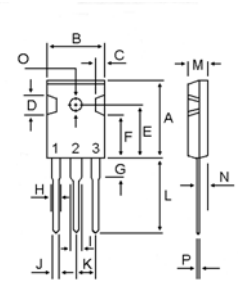
60 AMPERES
30-60 VOLTS



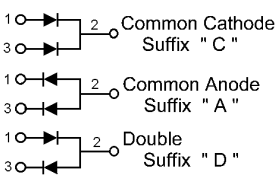
TO-3P

Features

- ∗Low Forward Voltage.
- ∗Low Switching noise.
- ∗High Current Capacity
- ∗Guarantee Reverse Avalanche.
- ∗Guard-Ring for Stress Protection.
- ∗Low Power Loss & High efficiency.
- ∗150℃ Operating Junction Temperature
- ∗Low Stored Charge Majority Carrier Conduction.
- ∗Plastic Material used Carries Underwriters Laboratory
- ∗Flammability Classification 94V-O
- ∗*Pb free*
- ∗*In compliance with EU RoHs directives*



DIM	MILLIMETERS	
	MIN	MAX
A	20.63	22.38
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.81	15.22
F	11.72	12.84
G	4.20	4.50
H	1.82	2.46
I	2.92	3.23
J	0.89	1.53
K	5.26	5.66
L	18.50	21.50
M	4.68	5.36
N	2.40	2.80
O	3.25	3.65
P	0.55	0.70



MAXIMUM RATINGS

Characteristic	Symbol	S60D						Unit
		30	35	40	45	50	60	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	30	35	40	45	50	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	21	25	28	32	35	42	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),T_C=100℃	$I_{F(AV)}$	30 60						A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	60						A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	400						A
Operating and Storage Junction Temperature Range	T_J , T_{STG}	-65 to +150						℃

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta j\text{-}c}$	2.0	℃/w

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	S60D						Unit
		30	35	40	45	50	60	
Maximum Instantaneous Forward Voltage (I_F =30 Amp T_C = 25℃) (I_F =30 Amp T_C = 100℃)	V_F	0.65 0.58				0.75 0.72		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 100℃)	I_R	3.0 80						mA

FIG-1 FORWARD CURRENT DERATING CURVE

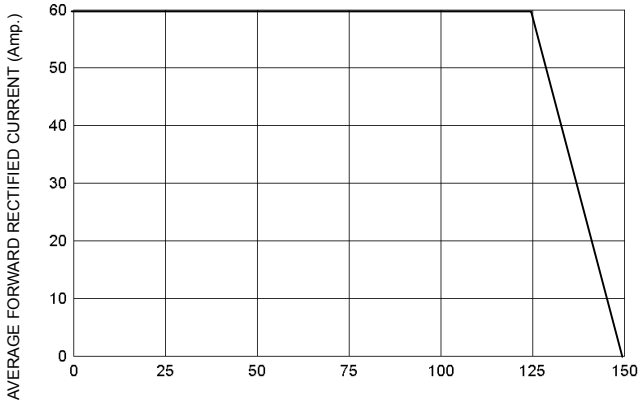


FIG-2 TYPICAL FORWARD CHARACTERISTICS

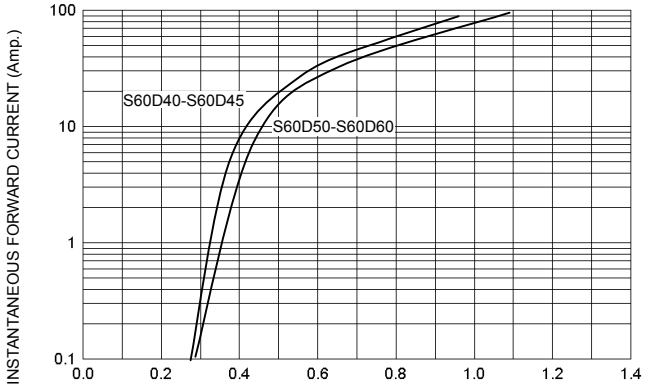


FIG-3 TYPICAL REVERSE CHARACTERISTICS

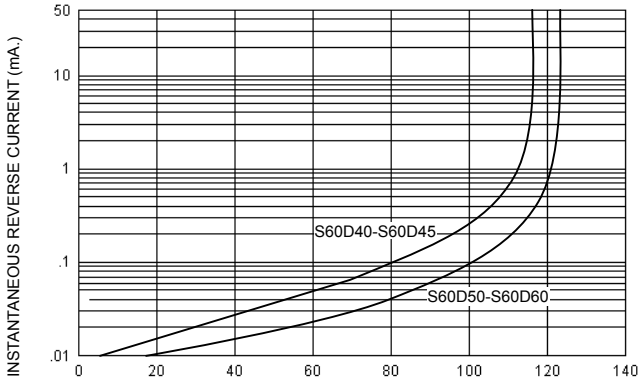


FIG-4 TYPICAL JUNCTION CAPACITANCE

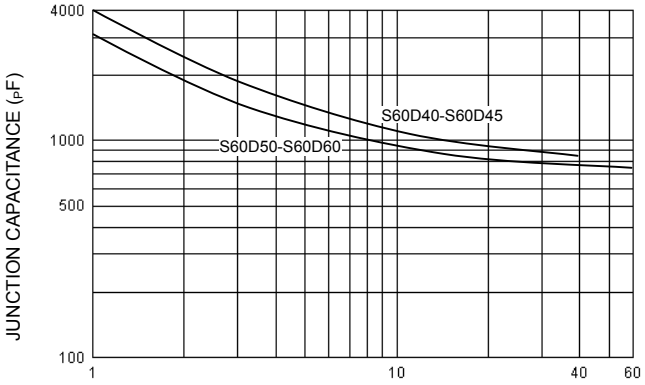
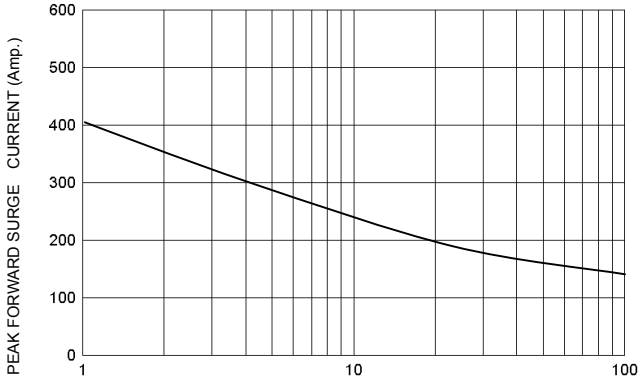


FIG-5 PEAK FORWARD SURGE CURRENT



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